



Super miniature design, SOP (1Form A/1Form B) 8-pin type. Controls load voltage 60V, 350V.

9.37 .369 12.1 .083

mm inch



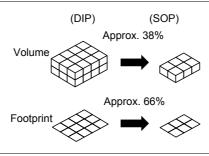
FEATURES

1. 60V type couples high capacity (0.45A) with low on-resistance (1 Ω).

Item	GU SOP (1 Form A/ 1 Form B type) type		
Part No.	AQW610S	AQW612S	
Load voltage	350V	60V	
Continuous load current	0.1A	0.45A	
ON resistance (typ.)	18Ω	1Ω	

2. 2 channels in super miniature design The device comes in a super-miniature

SO package measuring (W) $4.4 \times$ (L) $9.37 \times$ (H) 2.1 mm (W) $.173 \times$ (L) $.369 \times$ (H) .083 inch —approx. 38% of the volume and 66% of the footprint size of DIP type PhotoMOS relays.



🔊 3. Tape and reel

The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines. Applicable for 1 Form A 1 Form B use as well as two independent 1 Form A and 1 Form B use

GU PhotoMOS (AQW61OS)

Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion

4. Low-level off-state leakage current

TYPICAL APPLICATIONS

- Power supply
- Measuring equipment
- Security equipment
- Telephone equipment
- Computer input machine
- Industrial robots
- High-speed inspection machines

TYPES

1. AC/DC type

Output rating*		Part	Decking quantity in tang and re-		
Load voltage Load current		Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	Packing quantity in tape and reel	
60 V	450 mA	AQW612SX	AQW612SZ	1,000 pcs.	
350 V	100 mA	AQW610SX	AQW610SZ	1,000 pcs.	

*Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube. (Part No. suf x "X" or "Z" is not needed when ordering; Tube: 50 pcs.; Case: 1,000 pcs.)

(2) For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. AC/DC type

1. Absolute maximum ratings (Ambient temperature : 25°C 77°F)

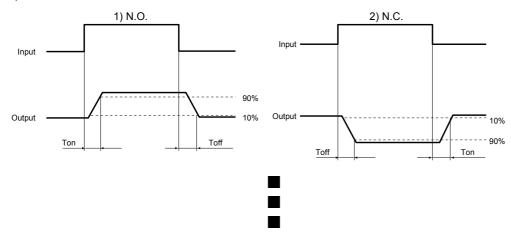
	• •	· · · · · ·	,		
	Item	Symbol	AQW612S	AQW610S	Remarks
Input	LED forward current	١F	50 mA		
	LED reverse voltage	VR	5 V		
	Peak forward current	IFP	1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW		
Output	Load voltage (peak AC)	VL	60 V	350 V	
	Continuous load current	l.	0.45 A (0.55 A)	0.1 A (0.13 A)	Peak AC, DC (): in case of using only 1a or 1b, 1 channel
	Peak load current	Ipeak	1.5 A	0.3 A	100 ms (1 shot), V∟ = DC
	Power dissipation	Pout	600 mW		
Total power dissipation	tion	Ρτ	650	mW	
I/O isolation voltage)	Viso	1,500	V AC	
Temperature limits	Operating	Topr	−40°C to +85°C −40°F to +185°F		Non-condensing at low temperatures
	Storage	Tstg	-40°C to +100°C -40°F to +212°F		

GU PhotoMOS (AQW61OS)

	Item		Symbol	AQW612S	AQW610S	Condition
Input LED operate current LED reverse current LED dropout voltage	LED operate	Typical	1	0.9 mA		l∟ = Max.
	current	Maximum	IFon	3 mA		
	LED reverse Minimu	Minimum		0.4 mA		l∟ = Max.
	current	Typical	IFoff	0.8 mA		
	LED dropout	Typical	VF	1.25 V (1.14 V at I⊧ = 5 mA)		I⊧ = 50 mA
	Maximum	m V _F 1.5 V		5 V	_ IF = 50 IIIA	
On resistance Output Off state leakag current		Typical		1 Ω	18 Ω	l⊧ = 5 mA (N.O.)
	On resistance	Maximum	Naximum Ron	2.5 Ω	25 Ω	I⊧= 0 mA (N.C.) I∟ = Max. Within 1 s on time
	Off state leakage current	Maximum	lleak	1 μΑ		I⊧ = 0 mA (N.O.) I⊧= 5 mA (N.C.) V∟ = Max.
Transfer characteristics I/O cap Initial I	Operate time*	Typical	- Ton	0.65 ms (N.O.), 0.9 ms (N.C.)	0.28 ms (N.O.), 0.52 ms (N.C.)	I⊧ = 0 mA → 5 mA I∟ = Max.
	Operate time	Maximum	Ion	3.0 ms	1.0 ms	
	Reverse time* Typical Maximum	Toff	0.08 ms (N.O.), 0.2 ms (N.C.)	0.04 ms (N.O.), 0.23 ms (N.C.)	I⊧ = 5 mA → 0 mA	
		Maximum	I off	1.0 ms	1.0 ms	I∟ = Max.
	I/O capacitance	Typical	Ciso	0.8 pF		f = 1 MHz V _B = 0 V
		Maximum	Ciso	1.5 pF		
	Initial I/O isolation resistance	Minimum	Riso	1,000 MΩ		500 V DC

Note: Recommendable LED forward current I_F = 5 mA.

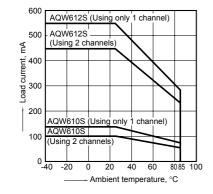
*Operate/Reverse time



REFERENCE DATA

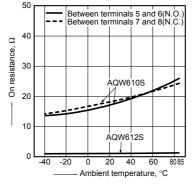
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C –40°F to +185°F



2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

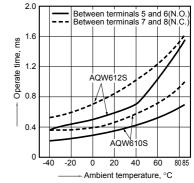


3. Operate time vs. ambient temperature characteristics

LED current: 5 mA;

Load voltage: Max. (DC);

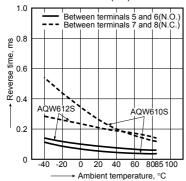
Continuous load current: Max. (DC)



GU PhotoMOS (AQW61OS)

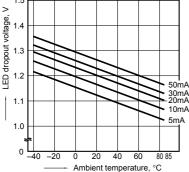
4. Reverse time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



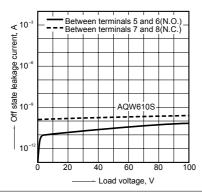
7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA

15



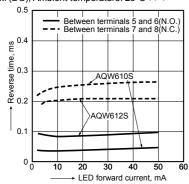
9-(1). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



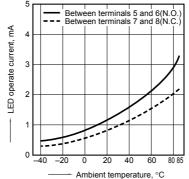
11. Reverse time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



5. LED operate current vs. ambient temperature characteristics Load voltage: Max. (DC);

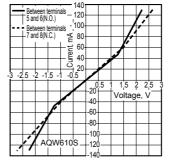
Continuous load current: Max. (DC)



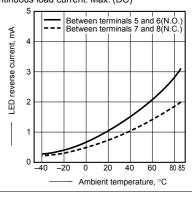
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;

Ambient temperature: 25°C 77

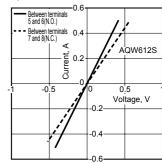


6. LED reverse current vs. ambient temperature characteristics Load voltage: Max. (DC); Continuous load current: Max. (DC)



8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



10. Operate time vs. LED forward current

Max. (DC); Ambient temperature: 25°C 77°F

QW6105

10 20 30

AQW612S

- - - -

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current:

Between terminals 5 and 6(N.O.) Between terminals 7 and 8(N.C.)

40 50

LED forward current, mA

60

characteristics

ms

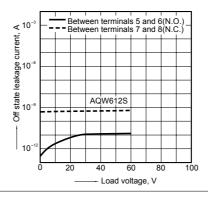
Operate time, 3

2

0

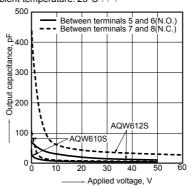
9-(2). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



All Rights Reserved © COPYRIGHT Matsushita Electric Works, Ltd.